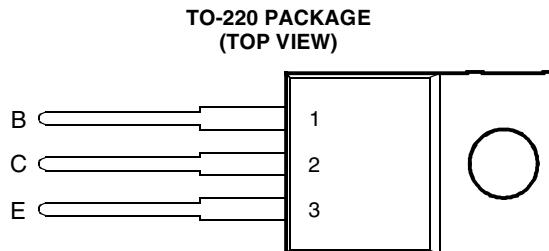


- Designed for Complementary Use with TIP135, TIP136 and TIP137
- 70 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- Minimum  $h_{FE}$  of 1000 at 4 V, 4 A



Pin 2 is in electrical contact with the mounting base.

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#### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ( $I_E = 0$ )	TIP130	$V_{CBO}$	60	V
	TIP131		80	
	TIP132		100	
Collector-emitter voltage ( $I_B = 0$ )	TIP130	$V_{CEO}$	60	V
	TIP131		80	
	TIP132		100	
Emitter-base voltage		$V_{EBO}$	5	V
Continuous collector current		$I_C$	8	A
Peak collector current (see Note 1)		$I_{CM}$	12	A
Continuous base current		$I_B$	0.3	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		$P_{tot}$	70	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		$P_{tot}$	2	W
Unclamped inductive load energy (see Note 4)		$\frac{1}{2}LI_C^2$	75	mJ
Operating junction temperature range		$T_j$	-65 to +150	°C
Storage temperature range		$T_{stg}$	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		$T_L$	260	°C

NOTES: 1. This value applies for  $t_p \leq 0.3$  ms, duty cycle  $\leq 10\%$ .

2. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of:  $L = 20$  mH,  $I_{B(on)} = 5$  mA,  $R_{BE} = 100$  Ω,  $V_{BE(off)} = 0$ ,  $R_S = 0.1$  Ω,  $V_{CC} = 20$  V.

#### PRODUCT INFORMATION

**electrical characteristics at 25°C case temperature**

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = 30 \text{ mA}$	$I_B = 0$	(see Note 5)	TIP130 TIP131 TIP132	60 80 100		V
$I_{CEO}$ Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$	$I_B = 0$		TIP130		0.5	
	$V_{CE} = 40 \text{ V}$	$I_B = 0$		TIP131		0.5	
	$V_{CE} = 50 \text{ V}$	$I_B = 0$		TIP132		0.5	
$I_{CBO}$ Collector cut-off current	$V_{CB} = 60 \text{ V}$	$I_E = 0$		TIP130		0.2	
	$V_{CB} = 80 \text{ V}$	$I_E = 0$		TIP131		0.2	
	$V_{CB} = 100 \text{ V}$	$I_E = 0$		TIP132		0.2	
	$V_{CB} = 60 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	TIP130		1	
	$V_{CB} = 80 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	TIP131		1	
	$V_{CB} = 100 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	TIP132		1	
$I_{EBO}$ Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$				5	mA
$h_{FE}$ Forward current transfer ratio	$V_{CE} = 4 \text{ V}$	$I_C = 1 \text{ A}$			500		
	$V_{CE} = 4 \text{ V}$	$I_C = 4 \text{ A}$	(see Notes 5 and 6)		1000		15000
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = 16 \text{ mA}$	$I_C = 4 \text{ A}$				2	V
	$I_B = 30 \text{ mA}$	$I_C = 6 \text{ A}$	(see Notes 5 and 6)			3	
$V_{BE}$ Base-emitter voltage	$V_{CE} = 4 \text{ V}$	$I_C = 4 \text{ A}$	(see Notes 5 and 6)			2.5	V
$C_{obo}$ Output capacitance	$V_{CB} = 10 \text{ V}$	$I_E = 0$				200	pF
$V_{EC}$ Parallel diode forward voltage	$I_E = 8 \text{ A}$	$I_B = 0$	(see Notes 5 and 6)			3.5	V

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

**thermal characteristics**

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			1.78	°C/W
$R_{\theta JA}$ Junction to free air thermal resistance			62.5	°C/W

**PRODUCT INFORMATION**

## TYPICAL CHARACTERISTICS

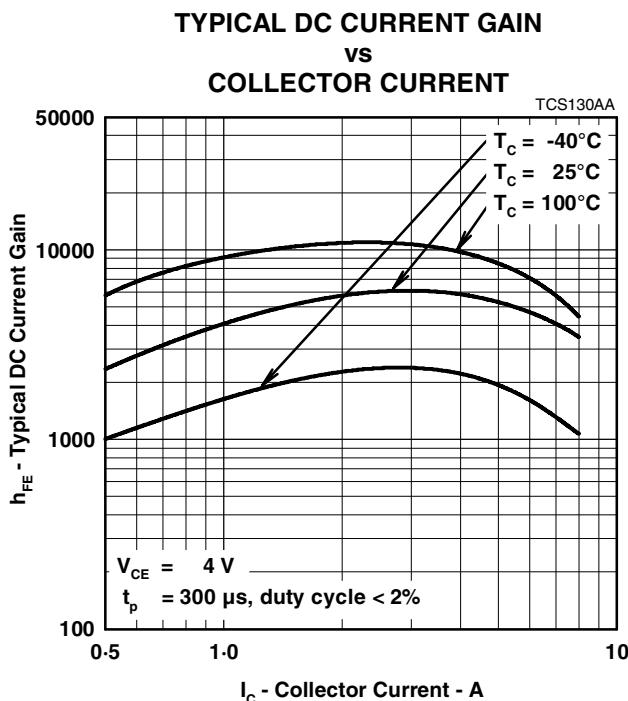


Figure 1.

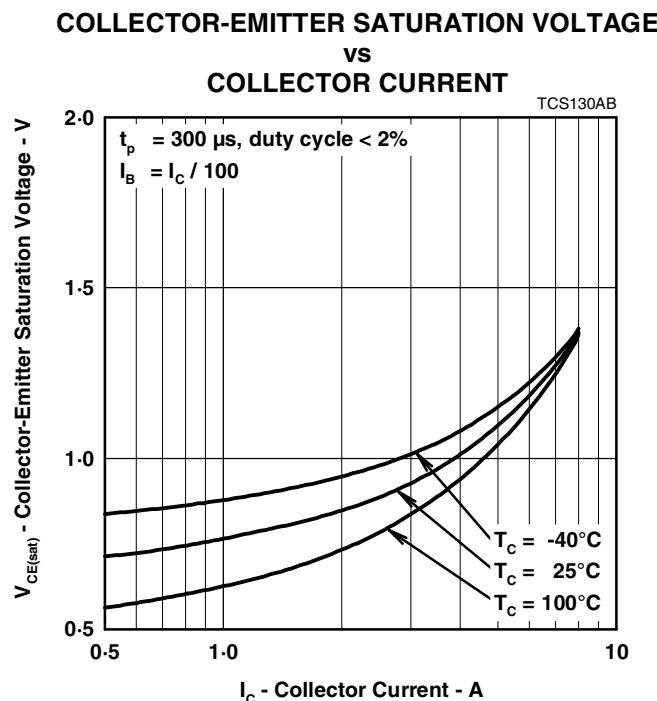


Figure 2.

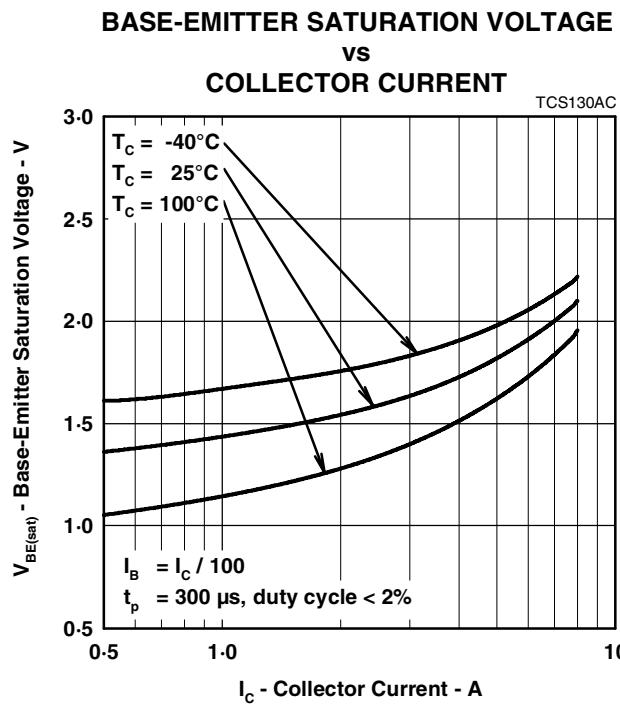


Figure 3.

**PRODUCT INFORMATION**

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Specifications are subject to change without notice.

### MAXIMUM SAFE OPERATING REGIONS

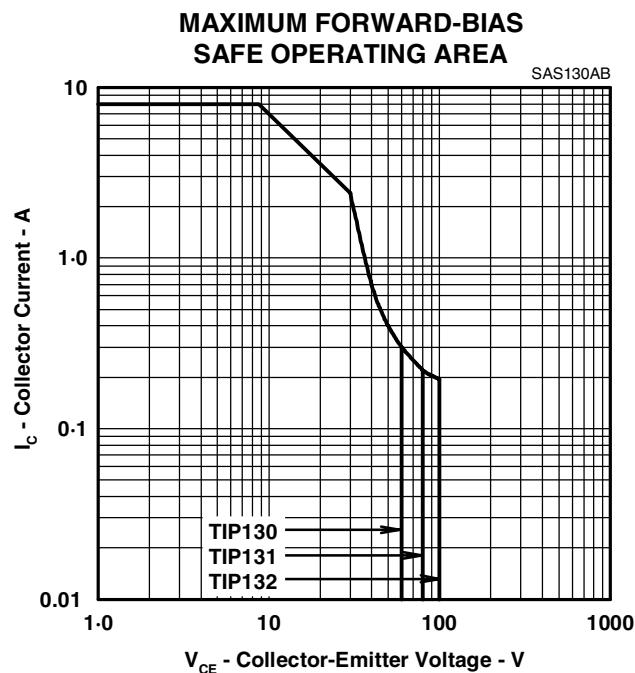


Figure 4.

### THERMAL INFORMATION

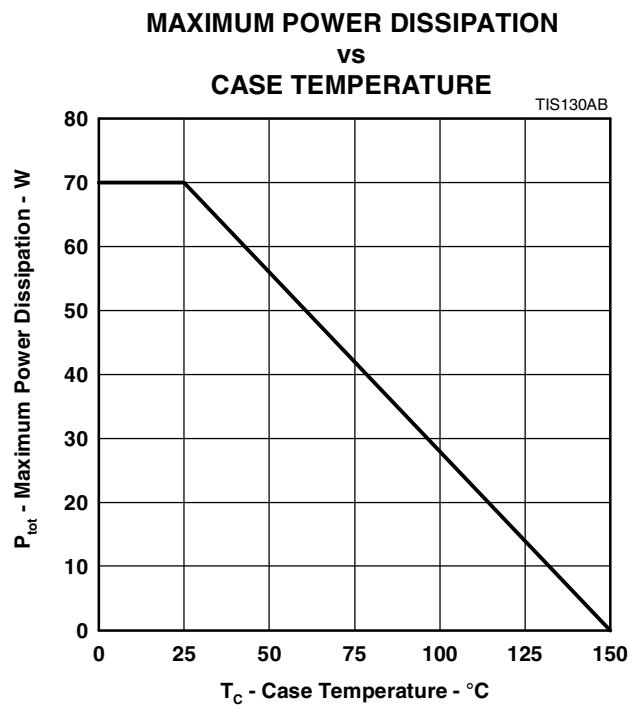


Figure 5.

### PRODUCT INFORMATION

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